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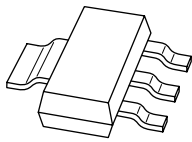
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Kind regards,

Team Nexperia



PBHV8115Z

150 V, 1 A NPN high-voltage low V_{CEsat} (BISS) transistor

Rev. 02 — 9 December 2008

Product data sheet

1. Product profile

1.1 General description

NPN high-voltage low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBHV9115Z.

1.2 Features

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- AEC-Q101 qualified
- Medium power SMD plastic package

1.3 Applications

- LED driver for LED chain module
- LCD backlighting
- High Intensity Discharge (HID) front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

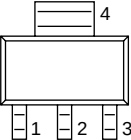
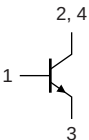
1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	150	V
I_C	collector current		-	-	1	A
h_{FE}	DC current gain	$V_{CE} = 10\text{ V};$ $I_C = 50\text{ mA}$	100	250	-	

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	base		
2	collector		
3	emitter		
4	collector		

sym016

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBHV8115Z	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223

4. Marking

Table 4. Marking codes

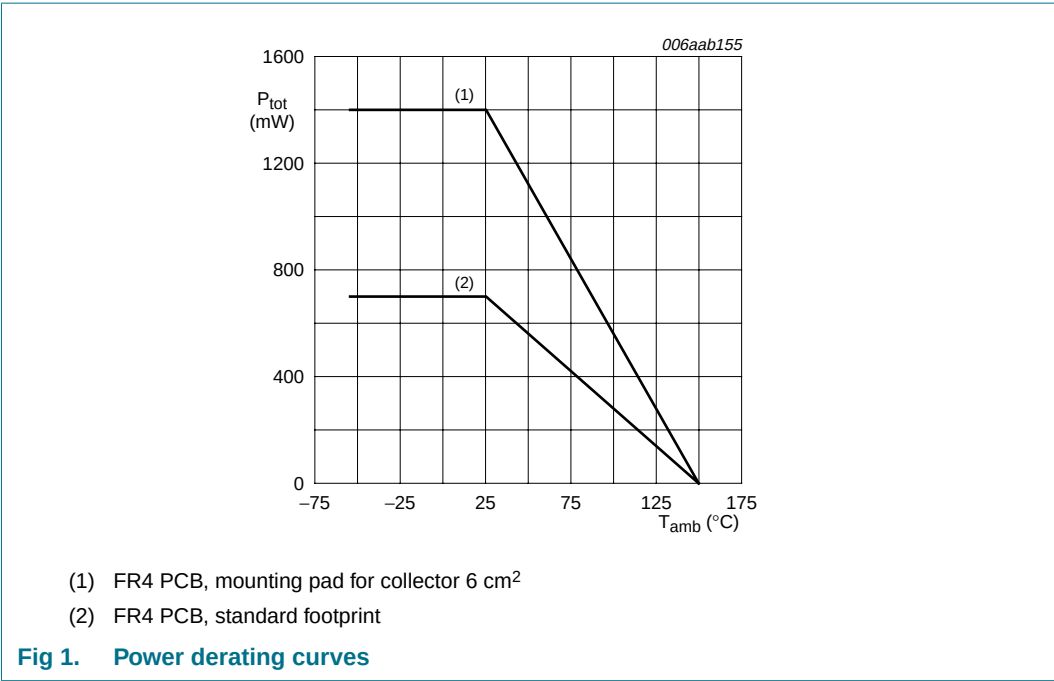
Type number	Marking code
PBHV8115Z	V8115Z

5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	400	V
V _{CEO}	collector-emitter voltage	open base	-	150	V
V _{EBO}	emitter-base voltage	open collector	-	6	V
I _C	collector current		-	1	A
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	2	A
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	-	400	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] -	0.7	W
			[2] -	1.4	W
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².

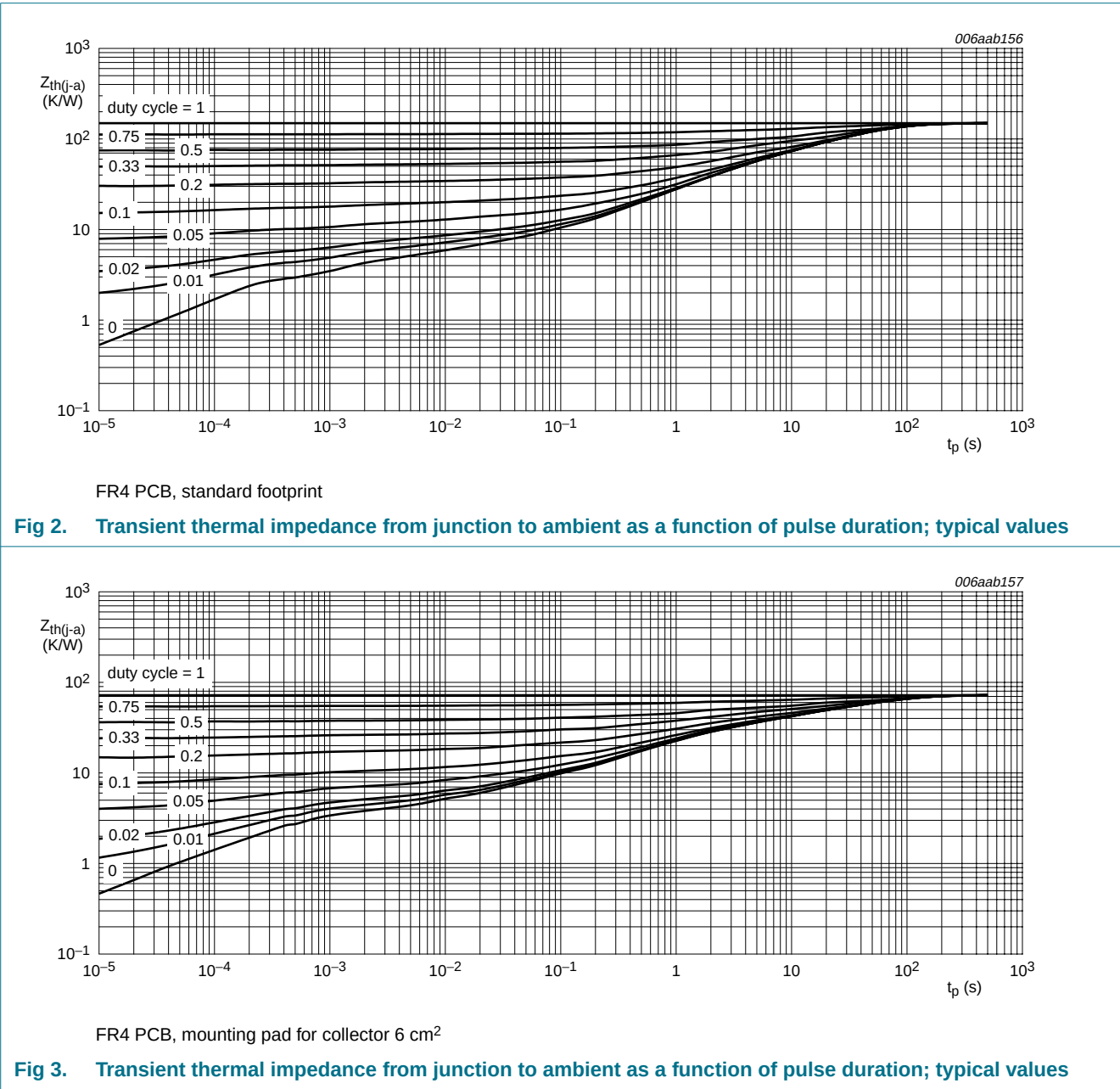


6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	175 K/W
			[2]	-	-	89 K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		-	-	20	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².



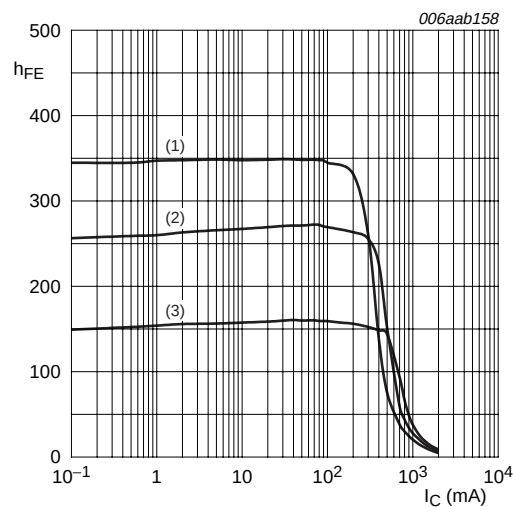
7. Characteristics

Table 7. Characteristics

$T_{amb} = 25^\circ\text{C}$ unless otherwise specified.

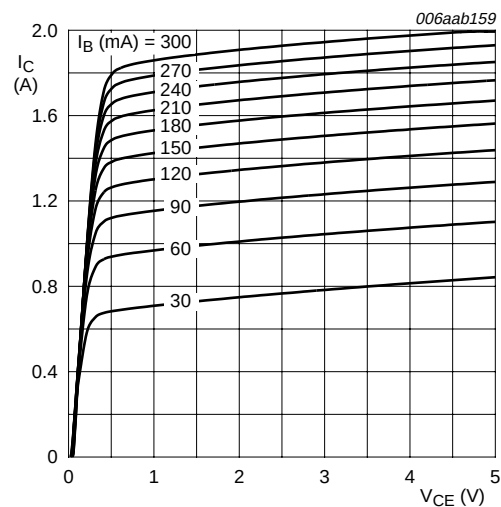
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = 120\text{ V}; I_E = 0\text{ A}$	-	-	100	nA
		$V_{CB} = 120\text{ V}; I_E = 0\text{ A}; T_j = 150^\circ\text{C}$	-	-	10	μA
I_{CES}	collector-emitter cut-off current	$V_{CE} = 120\text{ V}; V_{BE} = 0\text{ V}$	-	-	100	nA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 4\text{ V}; I_C = 0\text{ A}$	-	-	100	nA
h_{FE}	DC current gain	$V_{CE} = 10\text{ V}$				
		$I_C = 50\text{ mA}$	100	250	-	
		$I_C = 100\text{ mA}$	100	250	-	
		$I_C = 0.5\text{ A}$	[1] 50	160	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 100\text{ mA}; I_B = 10\text{ mA}$	-	40	60	mV
		$I_C = 100\text{ mA}; I_B = 20\text{ mA}$	-	33	50	mV
		$I_C = 1\text{ A}; I_B = 200\text{ mA}$	[1] -	225	350	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = 1\text{ A}; I_B = 200\text{ mA}$	[1] -	1.1	1.2	V
f_T	transition frequency	$V_{CE} = 10\text{ V}; I_E = 10\text{ mA}; f = 100\text{ MHz}$	-	30	-	MHz
C_c	collector capacitance	$V_{CB} = 20\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$	-	5.7	-	pF
C_e	emitter capacitance	$V_{EB} = 0.5\text{ V}; I_C = i_c = 0\text{ A}; f = 1\text{ MHz}$	-	150	-	pF
t_d	delay time	$V_{CC} = 6\text{ V}; I_C = 0.5\text{ A}; I_{Bon} = 0.1\text{ A}; I_{Boff} = -0.1\text{ A}$	-	7	-	ns
t_r	rise time		-	565	-	ns
t_{on}	turn-on time		-	572	-	ns
t_s	storage time		-	1530	-	ns
t_f	fall time		-	700	-	ns
t_{off}	turn-off time		-	2230	-	ns

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.02$.



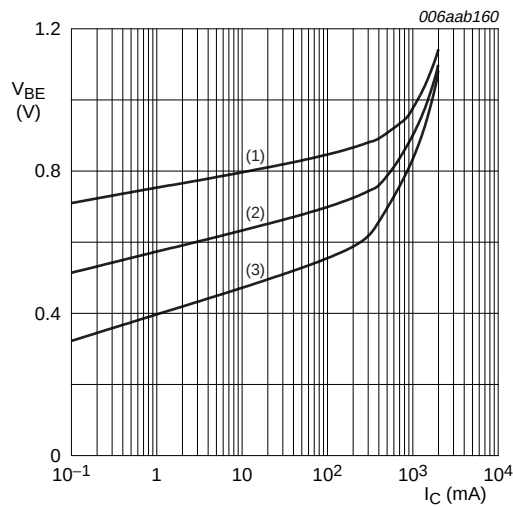
- $V_{CE} = 10\text{ V}$
- (1) $T_{amb} = 100\text{ °C}$
 - (2) $T_{amb} = 25\text{ °C}$
 - (3) $T_{amb} = -55\text{ °C}$

Fig 4. DC current gain as a function of collector current; typical values



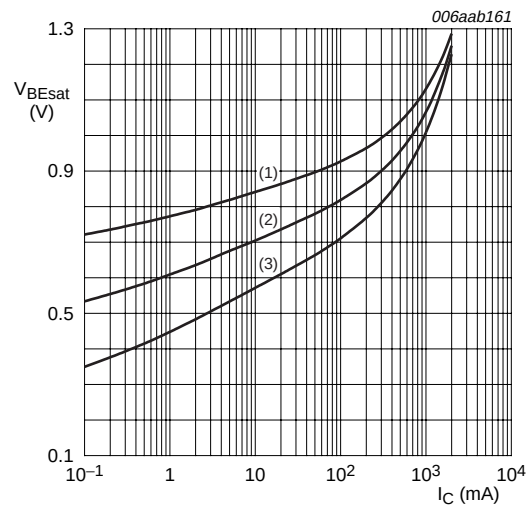
$T_{amb} = 25\text{ °C}$

Fig 5. Collector current as a function of collector-emitter voltage; typical values



- $V_{CE} = 10\text{ V}$
- (1) $T_{amb} = -55\text{ °C}$
 - (2) $T_{amb} = 25\text{ °C}$
 - (3) $T_{amb} = 100\text{ °C}$

Fig 6. Base-emitter voltage as a function of collector current; typical values



- $I_C/I_B = 5$
- (1) $T_{amb} = -55\text{ °C}$
 - (2) $T_{amb} = 25\text{ °C}$
 - (3) $T_{amb} = 100\text{ °C}$

Fig 7. Base-emitter saturation voltage as a function of collector current; typical values

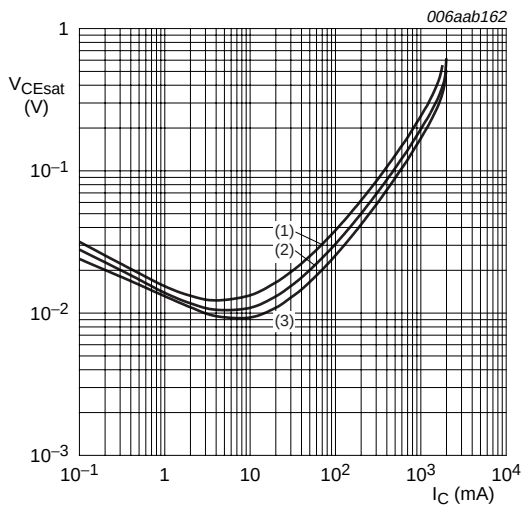


Fig 8. Collector-emitter saturation voltage as a function of collector current; typical values

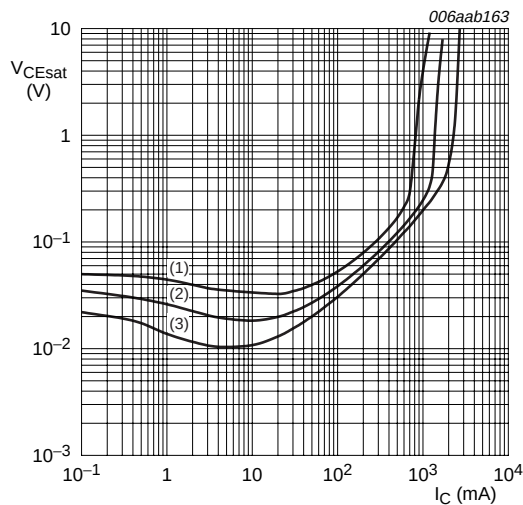


Fig 9. Collector-emitter saturation voltage as a function of collector current; typical values

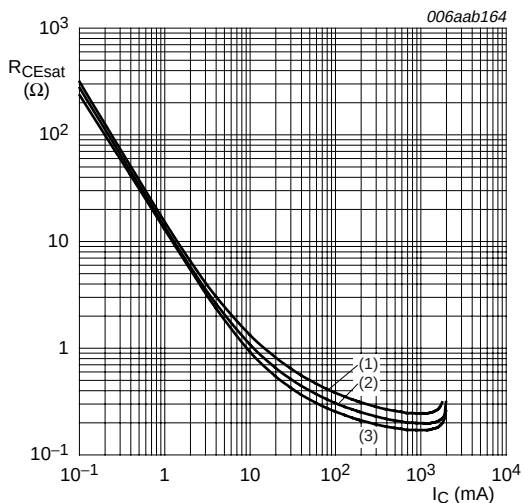


Fig 10. Collector-emitter saturation resistance as a function of collector current; typical values

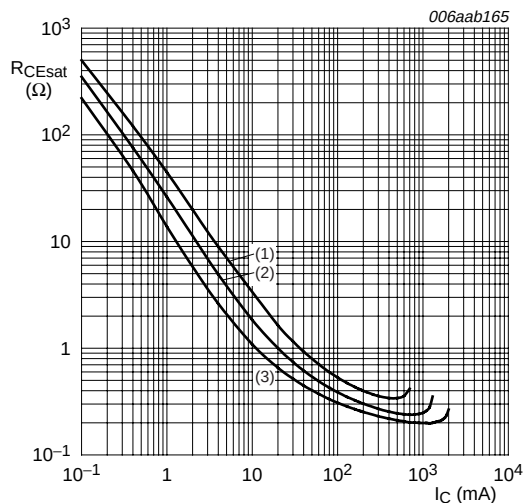
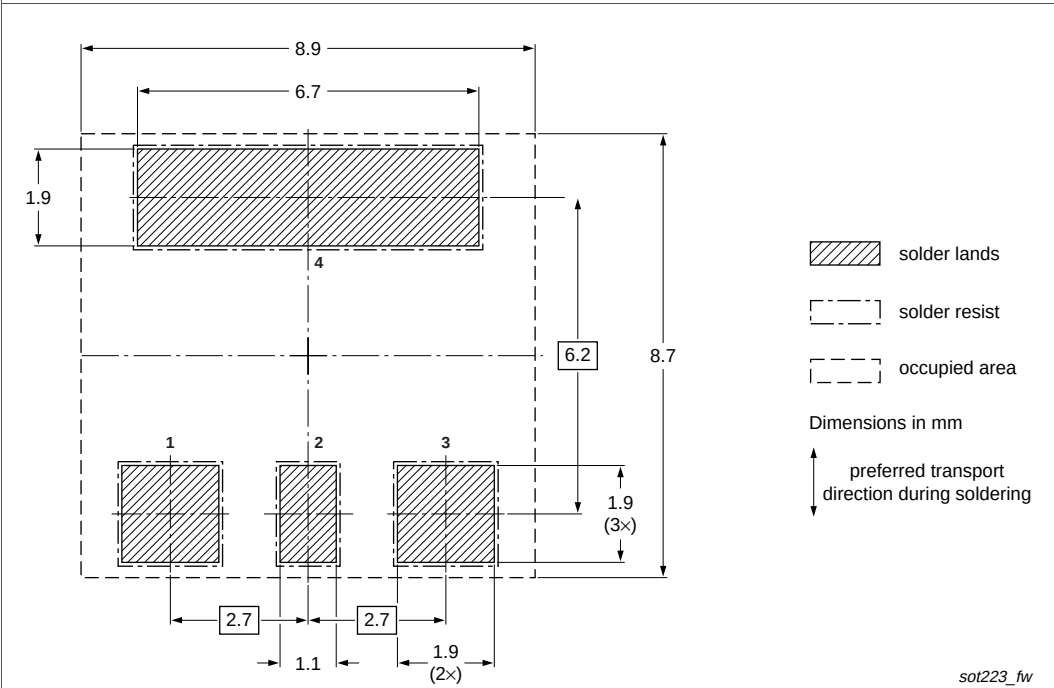
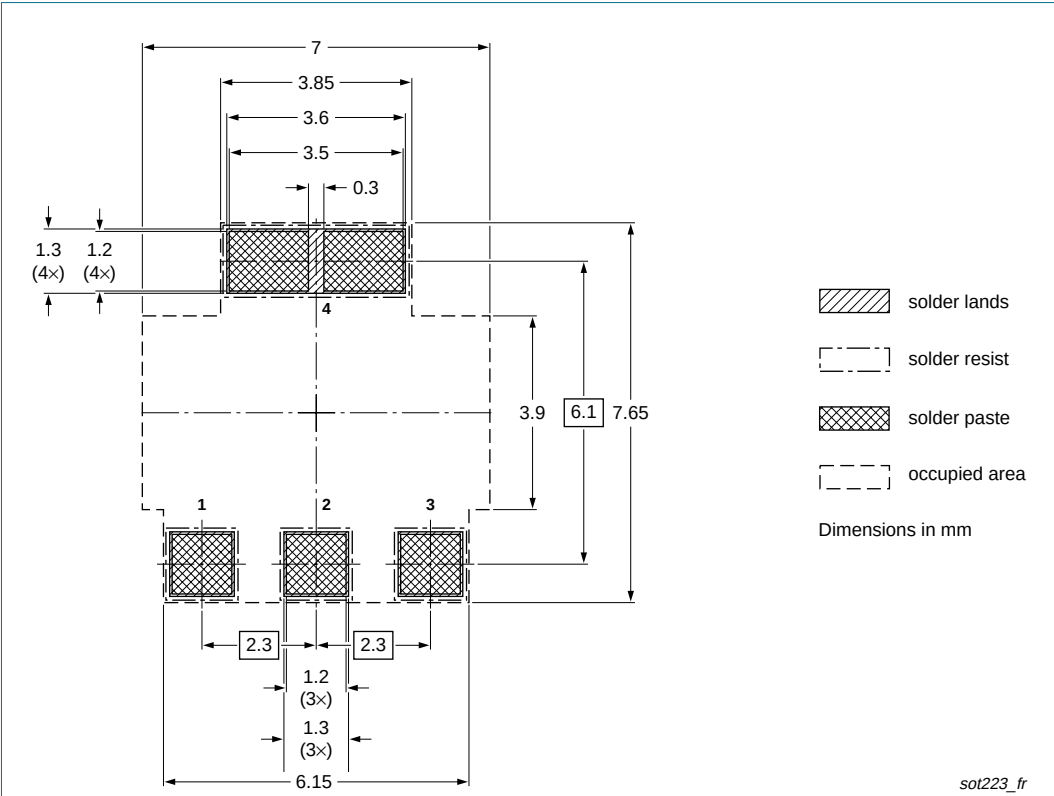


Fig 11. Collector-emitter saturation resistance as a function of collector current; typical values

11. Soldering



12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBHV8115Z_2	20081209	Product data sheet	-	PBHV8115Z_1
Modifications:	• Table 5: I_{BM} maximum value changed from 100 mA to 400 mA • Figure 5: amended • Section 13 "Legal information": updated			
PBHV8115Z_1	20080205	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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